TOSHIBA Transistor Silicon PNP Epitaxial Type

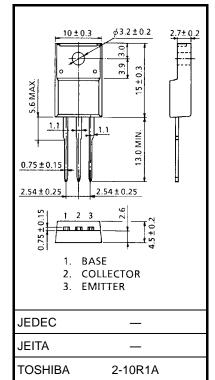
# 2SA1837

### Power Amplifier Applications Driver Stage Amplifier Applications

- High transition frequency:  $f_T = 70 \text{ MHz}$  (typ.)
- Complementary to 2SC4793

#### Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	-230	V	
Collector-emitter voltage		V <sub>CEO</sub>	-230	V	
Emitter-base voltage		V <sub>EBO</sub>	-5	V	
Collector current		Ι <sub>C</sub>	-1	А	
Base current		Ι <sub>Β</sub>	-0.1	А	
Collector power dissipation	Ta = 25°C	Pc	2.0	W	
	Tc = 25°C	ГС	20		
Junction temperature		Тј	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

Weight: 1.7 g (typ.)

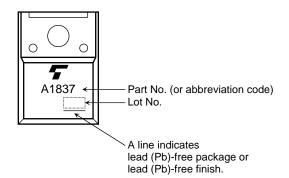
temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm

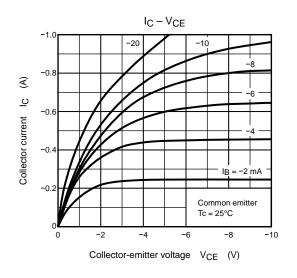
**Electrical Characteristics (Tc = 25°C)** 

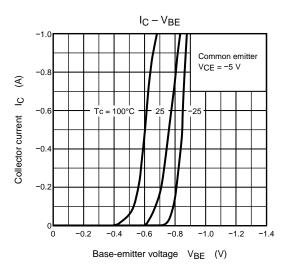
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -230 \text{ V}, I_E = 0$	_	_	-1.0	μA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 V, I_C = 0$	_	_	-1.0	μA
Collector-emitter breakdown voltage	V (BR) CEO	$I_{\rm C} = -10 \text{ mA}, I_{\rm B} = 0$	-230	_	—	V
DC current gain	h <sub>FE</sub>	$V_{CE} = -5 V, I_C = -100 mA$	100	_	320	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	$I_{\rm C} = -500$ mA, $I_{\rm B} = -50$ mA	_	_	-1.5	V
Base-emitter voltage	V <sub>BE</sub>	$V_{CE} = -5 V, I_C = -500 mA$	_	_	-1.0	V
Transition frequency	f <sub>T</sub>	$V_{CE} = -10 \text{ V}, \text{ I}_{C} = -100 \text{ mA}$	_	70	_	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -10 V$ , $I_C = 0$ , $f = 1 MHz$		30		pF

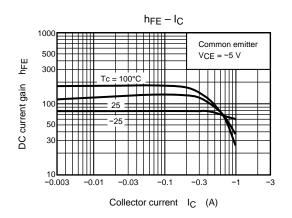
#### Marking

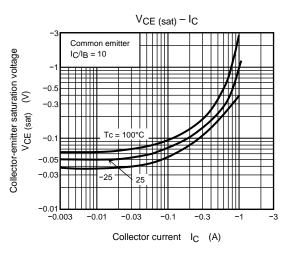


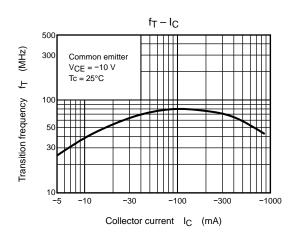
## **TOSHIBA**

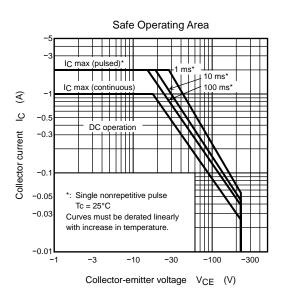












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